

## **Amendments to the Claims:**

This listing of claims will replace all prior versions, and listings, of claims in the application.

1. (Currently amended) A CPP giant magnetoresistive head comprising:  
lower and upper shield layers with a predetermined shield distance therebetween; and  
a giant magnetoresistive (GMR) element disposed between the upper and lower shield layers, the GMR element having a group of adjacent parallel layers, the group comprising a pinned magnetic layer, a free magnetic layer and a nonmagnetic layer disposed between the pinned magnetic layer and the free magnetic layer, the GMR element being free of an antiferromagnetic layer parallel to any layers of the group of adjacent parallel layers, wherein a current flows in a direction perpendicular to a film plane of the giant magnetoresistive element, and  
wherein the pinned magnetic layer extends to a rear of the nonmagnetic layer and the free magnetic layer, in a height direction, and a dimension of the pinned magnetic layer in a height direction is larger than that in a track width direction.
2. (Previously presented) The CPP giant magnetoresistive head according to claim 1, wherein the pinned magnetic layer comprises a magnetic material having a positive magnetostriction constant or a magnetic material having high coercive force, and an end of the pinned magnetic layer is exposed at a surface facing a recording medium.
3. (Previously presented) The CPP giant magnetoresistive head according to claim 1, wherein the pinned magnetic layer has a laminated ferrimagnetic structure comprising a first pinned magnetic layer and a second pinned magnetic layer which are laminated with a nonmagnetic intermediate layer disposed therebetween, and the first and second pinned magnetic layers partially or entirely comprises Fe-Co-Cu (wherein Fe > 10 atomic percent, Co > 30 atomic percent, and Cu > 5 atomic

percent), Fe-Co-Cu-X (wherein X is at least one element of Pt, Pd, Mn, Si, Au, and Ag), or Co<sub>2</sub>MnY (wherein Y is at least one element of Ge, Si, Sn, and Al).

4. (Withdrawn) The CPP giant magnetoresistive head according to claim 1, further comprising an antiferromagnetic layer provided in a rear of the giant magnetoresistive element in the height direction, for pinning the magnetization direction of the pinned magnetic layer in the height direction.

5. (Withdrawn) The CPP giant magnetoresistive head according to claim 4, wherein the antiferromagnetic layer is an insulating antiferromagnetic layer comprising Ni-O or  $\alpha$ -Fe<sub>2</sub>O<sub>3</sub>.

6. (Withdrawn) The CPP giant magnetoresistive head according to claim 4, wherein the antiferromagnetic layer comprises an insulating antiferromagnetic comprising Ni-O or  $\alpha$ -Fe<sub>2</sub>O<sub>3</sub> and an antiferromagnetic metal layer interposed between the insulating antiferromagnetic layer and the pinned magnetic layer.

7. (Original) The CPP giant magnetoresistive head according to claim 1, further comprising large-area nonmagnetic metal films provided between the giant magnetoresistive element and the lower shield layer and between the giant magnetoresistive element and the upper shield layer, respectively, so that the large-area nonmagnetic metal films are in direct contact with the pinned magnetic layer and the free magnetic layer and have larger areas than those of the pinned magnetic layer and the free magnetic layer, respectively.

8. (Original) The CPP giant magnetoresistive head according to claim 7, wherein the large-area nonmagnetic metal film disposed between the giant magnetoresistive element and the lower shield layer comprises any one of Ta/Cu, Ta/Ru/Cu, Ta/Cr, Ta/Ni-Cr, Ta/(Ni-Fe)-Cr, and Cr, and when the composition contains Cr, the Cr content exceeds 20 atomic percent.

9. (Currently amended) A CPP giant magnetoresistive head comprising;  
lower and upper shield layers with a predetermined shield distance  
therebetween; and  
a giant magnetoresistive (GMR) element disposed between the upper and  
lower shield layers, the GMR element having a group of adjacent parallel layers, the  
group comprising a pinned magnetic layer, a free magnetic layer and a nonmagnetic  
layer disposed between the pinned magnetic layer and the free magnetic layer, the  
GMR element being free of an antiferromagnetic layer parallel to any layers of the group  
of adjacent parallel layers, wherein a current flows in a direction perpendicular to a film  
plane of the giant magnetoresistive element; and  
wherein the pinned magnetic layer comprises a magnetic material having  
a positive magnetostriction constant or a magnetic material having high coercive force,  
and an end of the pinned magnetic layer is exposed at a surface facing a recording  
medium.

10. (Previously presented) The CPP giant magnetoresistive head according  
to claim 9, wherein a dimension of the pinned magnetic layer in a height direction is  
larger than the dimension in a track width direction.

11. (Previously presented) The CPP giant magnetoresistive head according  
to claim 9, wherein the pinned magnetic layer has a laminated ferrimagnetic  
structure comprising a first pinned magnetic layer and a second pinned magnetic  
layer which are laminated with a nonmagnetic intermediate layer disposed  
therebetween, and the first and second pinned magnetic layers partially or entirely  
comprises Fe-Co-Cu (wherein Fe > 10 atomic percent, Co > 30 atomic percent, and  
Cu > 5 atomic percent), Fe-Co-Cu-X (wherein X is at least one element of Pt, Pd,  
Mn, Si, Au, and Ag), or Co<sub>2</sub>MnY (wherein Y is at least one element of Ge, Si, Sn,  
and Al).

12. (Withdrawn) The CPP giant magnetoresistive head according to claim 9,  
further comprising an antiferromagnetic layer provided in a rear of the giant

magnetoresistive element in the height direction, for pinning the magnetization direction of the pinned magnetic layer in the height direction.

13. (Withdrawn) The CPP giant magnetoresistive head according to claim 12, wherein the antiferromagnetic layer is an insulating antiferromagnetic layer comprising Ni-O or  $\alpha$ -Fe<sub>2</sub>O<sub>3</sub>.

14. (Withdrawn) The CPP giant magnetoresistive head according to claim 12, wherein the antiferromagnetic layer comprises an insulating antiferromagnetic comprising Ni-O or  $\alpha$ -Fe<sub>2</sub>O<sub>3</sub> and an antiferromagnetic metal layer interposed between the insulating antiferromagnetic layer and the pinned magnetic layer.

15. (Original) The CPP giant magnetoresistive head according to claim 9, further comprising large-area nonmagnetic metal films provided between the giant magnetoresistive element and the lower shield layer and between the giant magnetoresistive element and the upper shield layer, respectively, so that the large-area nonmagnetic metal films are in direct contact with the pinned magnetic layer and the free magnetic layer and have larger areas than those of the pinned magnetic layer and the free magnetic layer, respectively.

16. (Original) The CPP giant magnetoresistive head according to claim 15, wherein the large-area nonmagnetic metal film disposed between the giant magnetoresistive element and the lower shield layer comprises any one of Ta/Cu, Ta/Ru/Cu, Ta/Cr, Ta/Ni-Cr, Ta/(Ni-Fe)-Cr, and Cr, and when the composition contains Cr, the Cr content exceeds 20 atomic percent.